# Extended Range ZVS Active-Clamped CurrentFed Full-Bridge Isolated Dc/Dc Converter for Fuel Cell Applications: Analysis, Design and Experimental Results 

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#### Abstract

This paper presents analysis and design of zerovoltage switching (ZVS) active-clamped current-fed full-bridge isolated de/dc converter for fuel cells applications. The designed converter maintains ZVS of all switches from full-load down to very light load condition over wide input voltage variation. Detailed operation, analysis, design, simulation and experimental results for the proposed design are presented. The additional auxiliary active clamping circuit absorbs the turn-off voltage spike limiting the peak voltage across the devices allowing the selection and use of low voltage devices with low on-state resistance. In addition, it also assists in achieving ZVS of semiconductor devices. The converter utilizes the energy stored in the transformer leakage inductance aided by its magnetizing inductance to maintain ZVS. ZVS range depends upon the design, in particular the ratio of leakage and magnetizing inductances of the transformer. Rectifier diodes operate with zero-current switching. An experimental converter prototype rated at 500 W has been designed, built and tested in the laboratory to verify the analysis, design and performance for wide variations in input voltage and load.


Index Terms- Fuel Cells, High-frequency DC/DC Converter, Zero voltage switching (ZVS), Renewable energy systems

## I. Introduction

CLEAN and green energy for distributed generation and modern/future transportation system has been of increasing interest to the academic and industrial researchers or community for sustainable and smart living. Power converter is an essential interface for the conversion of nonconventional energy sources into useful and regulated electrical ac or dc form. Power converter is a weak link and its efficiency determines the utilization of the source and controls the power output. Its cost, volume, and weight are the

[^0]deciding factors for the overall cost and volume of the installation system. Therefore, the design and development of low cost, high-efficient and small size power conversion systems is still an attention of researchers [1-2]. Even though renewable energy sources like solar and wind energy are available free of cost, their output is not secure due to their intermittent nature. Fuel cells output is secure and continuous in all seasons as long as the continuity of fuel supply is maintained and produce heat as byproduct that can be used for co-generation/heating and thus increases the overall efficiency of the system. Distributed generation for standalone and gridtied applications for residential and remote power systems are important applications. Two-stage inverter, i.e. highfrequency (HF) transformer isolated dc/dc converter followed by an inverter has been adopted by industries and has been proposed with different configurations and modulations in literature to achieve the given objectives. HF transformer isolated $\mathrm{dc} / \mathrm{dc}$ converter [2-19] translates the low fuel cell stack voltage to higher than the peak of the utility line or inverter output voltage specification with necessary isolation. Soft-switching is necessary to operate the converter at HF and to realize small size, light weight and low cost converter. It reduces the thermal stress on the components, switching losses, and improves the efficiency, particularly at light load where the switching and conduction losses are comparable or switching losses dominate the conduction losses. Many dc/dc converter topologies have been presented for this application [2-35] but most of them are not able to maintain softswitching over the wide power variation and entire operating range of fuel-cell voltage. Converter presented in [25] is hardswitched and two devices are connected in parallel to improve the efficiency and switching frequency is 50 kHz . Interleaved current-fed full-bridge converter reported in [26] is a hardswitched converter and therefore operated at 10 kHz , which increases the size of magnetics/filters and therefore, of the converter. Full-bridge voltage-fed converter has several problems: rectifier diode ringing, duty cycle loss, snubber across secondary, pulsating current at input increases filter size and has limited zero-voltage switching (ZVS) range [14]. Many additional components are used to achieve ZVS in [28] which is not a simpler solution and exhibits lower efficiency.

A topology similar to [4] is presented in [29], but secondary side switches lose ZVS at light load and higher input voltage, the ZVS range is calculated in [14]. A non-isolated bidirectional converter with active-clamping has been proposed [30] for ZVS up to $40 \%$ load but operation with wide input voltage variation is not reported. A solution to achieve ZVS over 1:2 source voltage variation using several extra components is given [31] without discussing ZVS for variation in load.

A comparison of soft-switched $\mathrm{dc} / \mathrm{dc}$ converters for fuel cells to utility interface is given in [14] and it was shown that a two-inductor half-bridge current-fed isolated dc/dc converter with active-clamp [2, 13, 15, 17, 34-35] is suitable for such applications. Active-clamp snubs the voltage turn-off spike and aids in ZVS of HF switches but cannot maintain ZVS for the wide operating range of load and input voltage. Also, it has power limitation and is not modular. Full-bridge currentfed topology is modular in nature and is easy to be interleaved due to single inductor topology with less sensor requirements and less state variable and is suitable for high power. This topology has been discussed in [20-22]. It should be noted that the magnetizing inductance makes the transformer leakage inductance current continuous and also increases the number of state variables [21]. Therefore, the operation, analysis and design get modified due to the third state variable and this was completely neglected in the earlier analysis and design [20, 22]. However, the analysis and design for full range ZVS is not mentioned. To achieve ZVS for wide variation in input voltage and load while maintaining high efficiency has been a challenge, especially for low voltage higher current input applications. This paper introduces a design as a solution to cover ZVS for wide operating range. Hard-switching topology for low switching frequency operation is discussed in [23-24].

In this paper, an active-clamped current-fed full-bridge dcdc converter shown in Fig. 1 with wide/extended range ZVS design and analysis is proposed. This paper proposes a design without involving extra active and/or passive components. The proposed converter design maintains soft-switching for this wide operating range and maintains higher efficiency. The authors do not claim on the topology. It has been discussed in [20-22]. The analysis including magnetizing inductance effect is studied in [21]. However, the authors claim on the modified analysis (explaining mode by mode operation) along with the new design with optimum inductance ratio to maintain softswitching over wide input voltage and output power. Analytical equations have been reported to calculate the components' rating and the performance of the converter.
The objectives of this paper are to present the detailed operation, steady-state analysis, design, simulation and experimental results of this converter with extended ZVS range. Steady state operation and analysis during different intervals of operation of the converter including the effect of magnetizing inductance/current are given in Section II. A complete design procedure for extended range soft-switching illustrated by design example is presented in Section III. Simulation results using PSIM 9.0.4 are presented in Section

IV to verify the analysis and design. An experimental converter prototype rated at 500 W was built and tested in the laboratory to validate the design and to test the operation of the converter for wide variations in input voltage and load. Experimental results obtained are presented in Section IV.


Fig. 1. Active-clamped ZVS current-fed full-bridge DC-DC converter.

## II. Operation and Analysis of the Converter

The Steady-state operation and analysis of the proposed design including the effect of magnetizing inductance/current is presented in this Section. The following assumptions are made to study and understand the operation and analysis of the converter: 1) Input inductor $L$ is large so that the current through it is considered constant. 2) Clamp capacitor $C_{a}$ is large to maintain constant voltage across it. 3) All components including devices and diodes are ideal.

Steady-state operating waveforms are shown in Fig. 2. Switches $S_{1}$ and $S_{4}$ are operated by identical gating signals, and $S_{2}$ and $S_{3}$ are operated by the common gating signals. Gating signals of switch pair $S_{2}, S_{3}$ are shifted in phase by $180^{\circ}$ with gating signals of switch pair $S_{1}, S_{4}$ with an overlap. The overlap varies with duty cycle, which varies with input voltage variation. Fixed frequency duty cycle modulation is used for control. The duty cycle of the main switches is always kept greater than $50 \%$ to prevent increased circulating current through the auxiliary active-clamp circuit. Operation of converter with duty ratio below $50 \%$ results in unwanted conduction losses causing lower converter efficiency, particularly at partial load as the auxiliary circuit loss becomes comparable to the loss in the main switches. The switching frequency of auxiliary switch $S_{a x}$ is double of that of main switches. It is controlled by gating signal complementary to the main switches' gating signals. So, the duty cycle of the auxiliary switch is always less than $50 \%$. The operation of the converter during different intervals in a HF half cycle is explained using the equivalent circuits shown in Fig. 3.

Interval 1 (Fig. 3a; $\boldsymbol{t}_{\mathbf{0}}<\boldsymbol{t}<\boldsymbol{t}_{\mathbf{1}}$ ): In this interval, all four main switches $S_{1} \sim S_{4}$ are on. Auxiliary switch $S_{a x}$ is off. Input inductor $L$ is storing energy. Power is transferred to the load by the energy stored in the output filter capacitor $C_{0}$. Transformer magnetizing current circulates through its leakage inductance, given by

$$
\begin{equation*}
i_{l k}=i_{L m}^{\prime}=-I_{L m, p e a k}^{\prime} \tag{1}
\end{equation*}
$$

where $i_{l k}$ is transformer input or leakage inductance current, $i_{L m}^{\prime}$ is magnetizing current reflected to primary side and $I_{\text {Lm,peak }}^{\prime}$ is the peak value of magnetizing current, given by

$$
\begin{equation*}
I_{L m, p e a k}^{\prime}=\frac{n \cdot V_{0} \cdot T_{D R}}{2 \cdot L_{m}} \tag{2}
\end{equation*}
$$

where, $L_{l k}$ and $L_{m}^{\prime}$ are the leakage inductance and magnetizing inductance of the transformer referred to primary. $T_{D R}$ is rectifier diode conduction time.

Voltage across the auxiliary capacitor $C_{a}$ is

$$
\begin{equation*}
V_{C a}=\frac{V_{i n}}{2 \cdot(1-D)} \tag{3}
\end{equation*}
$$

Voltage across the auxiliary switch is

$$
\begin{equation*}
V_{S a x}=V_{C a}=\frac{V_{i n}}{2 \cdot(1-D)} \tag{4}
\end{equation*}
$$

Duty ratio of main switches $D=T_{o n} / T_{s} ; T_{o n}=$ conduction time of main switch and $T_{s}=$ switching time period.

Interval 2 (Fig. 3b; $\boldsymbol{t}_{\mathbf{1}}<\boldsymbol{t}<\boldsymbol{t}_{2}$ ): At $t=t_{1}$, main switches $S_{2}$ and $S_{3}$ are turned off. Current in the input boost inductor $\left(I_{i n}\right)$ is diverted into the auxiliary circuit path causing zero current through all main switches. The magnetizing current flows through leakage inductance $L_{l k}$, anti-parallel diodes $D_{1}, D_{4}$ of main switches $S_{1}$ and $S_{4}$. Therefore, switch currents through $S_{1}$ and $S_{4}$ quickly dips to negative, which is equivalent to peak value of the reflected magnetizing current. Device capacitances $C_{2}$ and $C_{3}$ of main switches $S_{2}$ and $S_{3}$ start charging and auxiliary switch snubber capacitor $C_{a \mathrm{x}}$ starts discharging linearly. On secondary side, rectifier diodes are reverse biased and power is still transferred to the load by the output filter capacitor. The constant current ( $I_{\text {Lm,peak }}^{\prime}$ ) continues to flow through magnetizing inductance. At the end of this interval, voltages across the main switch $S_{2}$ and auxiliary switch $S_{a x}$ reach $V_{S 2}\left(t_{2}\right)=V_{S 3}\left(t_{2}\right)=V_{o} / n$ and $V_{S a x}\left(t_{2}\right)=$ $V_{C a}-V_{o} / n$, respectively.

Interval 3 ( $\mathbf{F i g} . \mathbf{3 c} ; \boldsymbol{t}_{\mathbf{2}}<\boldsymbol{t}<\boldsymbol{t}_{\mathbf{3}}$ ): This interval is very short. Snubber capacitors which are partially charged in interval 2 , are still going through charging and discharging. The main switch voltages $v_{S 2}$ and $v_{S 3}$ increase from $V_{o} / n$ to $V_{C a}$. A positive voltage equal to ( $V_{C 2}-V_{o} / n$ ) appears across the transformer leakage inductance and current through it, $i_{l k}$ rises linearly. Output voltage $V_{o}$ appears across the magnetizing inductance $L_{m}$ and current through it starts increasing linearly. Rectifier diodes $D R_{1}$ and $D R_{4}$ are forward biased and start conducting when the leakage inductance current $i_{l k}$ rises above $i_{L m}^{\prime}$ and power is transferred to the load. The leakage inductance current $i_{l k}$ is given by

$$
\begin{equation*}
i_{l k}=-I_{L m, p e a k}^{\prime}+\frac{v_{S 2}-\left(V_{o} / n\right)}{L_{l k}} \cdot\left(t-t_{2}\right) \tag{5}
\end{equation*}
$$

The magnetizing inductance current $i_{L m}$ is given by

$$
\begin{equation*}
i_{L m}=-I_{L m, p e a k}+\frac{V_{o}}{L_{m}} \cdot\left(t-t_{2}\right) \tag{6}
\end{equation*}
$$

$I_{L m, p}$ is the peak current through magnetizing inductance (on secondary side). Current through the switch $\mathrm{S}_{1}$ is given by

$$
\begin{equation*}
i_{S 1}=-I_{L m, p e a k}^{\prime}+\frac{v_{S 2}-\left(V_{o} / n\right)}{L_{l k}} \cdot\left(t-t_{2}\right) \tag{7}
\end{equation*}
$$

The auxiliary clamp capacitor current $i_{C a}$ decreases linearly and the balance $I_{i n}-i_{C a}$ is transferred to transformer through the switches $S_{1}$ and $S_{4}$ and thus to the load.
At the end of this interval, the auxiliary switch snubber capacitor $C_{a x}$ is discharged completely to zero and $C_{2}$ and $C_{3}$ are charged to its full voltage, equal to $V_{C a}$. Final values are: $v_{C a x}\left(t_{3}\right)=v_{S a x}\left(t_{3}\right)=0 ; v_{S 2}\left(t_{3}\right)=v_{C 2}\left(t_{3}\right)=v_{S 3}\left(t_{3}\right)=v_{C 3}\left(t_{3}\right)=V_{C a}=\frac{V_{\text {in }}}{2(1-D)}$
Interval 4 (Fig. 3d; $\boldsymbol{t}_{3}<\boldsymbol{t}<\boldsymbol{t}_{4}$ ): In this interval, the antiparallel body diode $D_{a x}$ of the auxiliary switch $S_{a x}$ starts conducting and $S_{a x}$ can be gated for ZVS turn on. Leakage inductance current $i_{l k}$ is increasing with the slope of [ $\left(V_{C a}-\right.$ $\left.\left.V_{o} / n\right) / L_{l k}\right]$. In this interval, switch current (through $S_{1}$ and $S_{4}$ ) changes direction to positive magnitude. Current through the magnetizing inductance is increasing with the same slope.
Transformer leakage inductance current $i_{l k}$ is given by

$$
\begin{equation*}
i_{l k}=i_{l k}\left(t_{3}\right)+\frac{V_{C a}-\left(V_{o} / n\right)}{L_{l k}} \cdot\left(t-t_{3}\right) \tag{8}
\end{equation*}
$$

Current through the switch $S_{1}$ is given by

$$
\begin{equation*}
i_{S 1}=i_{S 1}\left(t_{3}\right)+\frac{V_{C a}-\left(V_{o} / n\right)}{L_{l k}} \cdot\left(t-t_{3}\right) \tag{9}
\end{equation*}
$$

Magnetizing inductance current is given by

$$
\begin{equation*}
i_{L m}=i_{L m}\left(t_{3}\right)+\frac{V_{o}}{L_{m}} \cdot\left(t-t_{3}\right) \tag{10}
\end{equation*}
$$

Current through auxiliary capacitor during this interval decreases and is given by

$$
\begin{equation*}
i_{C a}=I_{C a, p e a k}-\frac{V_{C a}-\frac{V_{o}}{n}}{L_{l k}} \cdot\left(t-t_{3}\right) \tag{11}
\end{equation*}
$$

At the end of this interval, i.e., $t=t_{4}, i_{C a}$ reaches zero, $i_{l k}$ reaches $I_{i n}$ and also switch current $i_{S 1}$ reaches $I_{i n}$.
Final values are: $i_{l k}\left(t_{4}\right)=I_{i n} ; i_{C a}\left(t_{4}\right)=0 ; i_{S 1}\left(t_{4}\right)=i_{S 4}\left(t_{4}\right)=I_{i n}$.
Interval 5 (Fig. 3e; $\boldsymbol{t}_{4}<\boldsymbol{t}<\boldsymbol{t}_{5}$ ): In this interval, the auxiliary switch $S_{a x}$ is turned on with ZVS. Current $i_{l k}$ rises above $I_{i n}$ with the same slope as interval 4 and current $i_{C a}$ falls linearly below zero. Magnetizing current $i_{L m}$ is increasing with the same slope as interval 4. The equations for this interval are

$$
\begin{align*}
& i_{l k}=I_{i n}+\frac{\left(V_{C a}-\frac{V_{o}}{n}\right)}{L_{l k}} \cdot\left(t-t_{4}\right)  \tag{12}\\
& i_{S 1}=I_{i n}+i_{C a}  \tag{13}\\
& i_{C a}=I_{i n}-i_{l k}=-\frac{\left(V_{C a}-\frac{V_{o}}{n}\right)}{L_{l k}} \cdot\left(t-t_{4}\right) \tag{14}
\end{align*}
$$

Peak value of the switch current is given by:

$$
\begin{equation*}
I_{S 1, p e a k}=2 I_{i n}+\frac{n V_{o}}{f_{s} \cdot L_{m}} \cdot(1-D) \tag{15}
\end{equation*}
$$

At the end of this interval, current $i_{C a}$ rises to negative peak of $-\left(I_{i n}+\right.$ $\left.I_{L m p e a k}^{\prime}\right)$ and therefore the currents $i_{l k}$ and $i_{S 1}$ reaches their peak value. Final values: $i_{C a}\left(t_{5}\right)=-I_{C a, p e a k} ; i_{l k}\left(t_{5}\right)=I_{l k p e a k ;} ; i_{S 1}\left(t_{5}\right)=I_{S 1, \text { peak. }}$


Fig. 2. Steady state operating waveforms of current-fed full-bridge DC-DC converter with active-clamp.

(a)

(c)

(d)

(e)

(f)

(g)

(h)


Fig. 3. Equivalent circuits during different intervals of operation of the converter for the waveforms shown in Fig. 2.

Interval 6 (Fig. 3f; $\boldsymbol{t}_{5}<\boldsymbol{t}<\boldsymbol{t}_{\mathbf{6}}$ ): The auxiliary switch $S_{a x}$ is turned off at $t=t_{5}$. Current $i_{l k}$ charges $C_{a x}$ and discharges $C_{2}$ and $C_{3}$. The leakage inductance $L_{l k}$ resonates with snubber capacitors $C_{a x}$ and $C_{2}+C_{3}$. This time interval is very short and the leakage inductance current $i_{l k}$ drops by a small value. The resonant frequency is given by

$$
\begin{equation*}
\omega_{r}=\frac{1}{\sqrt{L_{l k} \cdot\left(C_{2}+C_{3}+C_{a x}\right)}} \tag{16}
\end{equation*}
$$

Voltage across the capacitor $C_{2}$ or switch $S_{2}$ is given by

$$
\begin{equation*}
v_{S 2}=V_{C a}-v_{S a x} \tag{17}
\end{equation*}
$$

where the voltage across the switch $S_{a x}$ (or capacitor $C_{a x}$ ) is given by

$$
\begin{gather*}
v_{S a x}=I_{l k, p e a k}^{\prime} \cdot \sqrt{\frac{L_{l k}}{\left(C_{2}+C_{3}+C_{a x}\right)}} \cdot \sin \left(\omega_{r} \cdot\left(t-t_{5}\right)\right)  \tag{18}\\
i_{l k}=I_{l k, p e a k} \cdot \cos \left(\omega_{r} \cdot\left(t-t_{5}\right)\right) \tag{19}
\end{gather*}
$$

Main switch current is given by

$$
\begin{equation*}
i_{S 1}=I_{S 1, p e a k} \cdot \cos \left(\omega_{r} \cdot\left(t-t_{5}\right)\right) \tag{20}
\end{equation*}
$$

At the end of this interval, $C_{2}$ and $C_{3}$ discharge to $V_{o} / n$ and $C_{a x}$ charges to $\left(V_{C a}-V_{o} / n\right)$. Final values are:
$v_{S a x}\left(t_{6}\right)=V_{C a}-V_{d} / n ; v_{S 2}\left(t_{6}\right)=V_{d} n ;$

Interval 7 (Fig. 3g; $\boldsymbol{t}_{\boldsymbol{6}}<\boldsymbol{t}<\boldsymbol{t}_{\boldsymbol{7}}$ ): Current $i_{l k}$ is still charging $C_{a x}$ and discharging $C_{2}$ and $C_{3}$ in a resonant fashion. It is short interval too and the current $i_{l k}$ decreases a very little in this interval. At the end of this interval, the capacitors $C_{2}$ and $C_{3}$ discharges completely to zero and capacitor $C_{a x}$ charges to its initial value. Final values are: $v_{S 2}\left(t_{7}\right)=0 ; v_{S a x}\left(t_{7}\right)=V_{C a}$.

Interval 8 (Fig. 3h; $\boldsymbol{t}_{7}<\boldsymbol{t}<\boldsymbol{t}_{\mathbf{8}}$ ): In this interval, anti-parallel body diodes $D_{2}$ and $D_{3}$ of main switches $S_{2}$ and $S_{3}$ respectively start conducting and now $S_{2}$ and $S_{3}$ can be gated for ZVS turn on. Current $i_{l k}$ decreases with a negative slope of $\left[V_{o} /\left(n \cdot L_{l k}\right)\right]$.

$$
\begin{align*}
i_{l k} & =I_{l k}\left(t_{7}\right)-\frac{V_{o}}{n \cdot L_{l k}} \cdot\left(t-t_{7}\right)  \tag{21}\\
i_{D 2} & =i_{l k}-I_{i n} \tag{22}
\end{align*}
$$

This interval ends when current $i_{l k}=I_{i n}$. Final values are: $i_{D 2}\left(t_{6}\right)=0 ; i_{l k}\left(t_{6}\right)=I_{i n}$.

Interval 9 (Fig. 3i; $\boldsymbol{t}_{\mathbf{8}}<\boldsymbol{t}<\boldsymbol{t}_{9}$ ): In this interval, switches $S_{2}$ and $S_{3}$ are turned on with ZVS. Currents $i_{S 2}$ and $i_{S 3}$ start increasing and the current $i_{l k}$ is decreasing with the same slope. Current $i_{l k}$ is transferred to the switches $S_{2}$ and $S_{3}$. The interval ends when current $i_{l k}$ equals to the current $i_{L m}^{\prime}$. Switch $S_{2}$ and $S_{3}$ current reaches to $I_{i n} / 2-I_{\text {Lm,peak }}^{\prime}$ and $S_{1}$ and $S_{4}$ current reaches to $I_{i n} / 2+I_{L m, p e a k}^{\prime}$.

$$
\begin{align*}
& i_{l k}=I_{i n}-\frac{V_{o}}{n \cdot L_{l k}} \cdot\left(t-t_{8}\right)  \tag{23}\\
& i_{S 2}=\frac{V_{o}}{n \cdot L_{l k}} \cdot\left(t-t_{8}\right)  \tag{24}\\
& i_{S 1}=I_{i n}-\frac{V_{o}}{n \cdot L_{l k}} \cdot\left(t-t_{8}\right) \tag{25}
\end{align*}
$$

Final values: $i_{S 2}\left(t_{9}\right)=I_{i n} / 2-I_{L m, p e a k}^{\prime} ; i_{S 1}\left(t_{9}\right)=I_{i n} / 2+I_{L m, p e a k}^{\prime} ;$ $i_{l k}\left(t_{9}\right)=i_{L m}^{\prime}\left(t_{9}\right)=I_{L m, p e a k}^{\prime}$.

For the next half cycle, the intervals are repeated in the same sequence with other symmetrical devices conducting to complete the full HF cycle. The analysis is done to obtain the design equations to design and select the components as well as to evaluate the converter's performance theoretically.

Based on this analysis, the design equations were derived and presented in next Section.

## III. Extended Range Soft-switching Design of the Converter

In this Section, converter design procedure for extended ZVS range is illustrated by a design example for the following specifications: Input voltage $V_{\text {in }}=22$ to 41 V , output voltage $V_{\mathrm{o}}=350 \mathrm{~V}$, output power $P_{\mathrm{o}}=500 \mathrm{~W}$, minimum load $=10 \%$ $(50 \mathrm{~W})$, switching frequency for H -bridge devices $f_{s}=100$ kHz and for auxiliary clamp switch is 200 kHz .
(1) Average input current is $I_{i n}=P_{\mathrm{o}} /\left(\eta V_{i n}\right)$. Assuming an ideal efficiency $\eta$ of $100 \%, I_{\text {in }}=22.7 \mathrm{~A}$.
(2) $D_{\max }$ is selected at minimum input voltage, i.e., $V_{i n}=22 \mathrm{~V}$ and full load which decides the maximum switch voltage rating $V_{S W(\max )}$ using

$$
\begin{equation*}
V_{s w, \max }=\frac{V_{i n}}{2 \cdot\left(1-D_{\max }\right)} \tag{26}
\end{equation*}
$$

For $D_{\max }=0.8, V_{S W(\max )}=55 \mathrm{~V}$.
(3) Inductor values $L_{l k}$ and $L_{m}$ : Selection of leakage inductance $L_{l k}$ and parallel inductance $L_{m}$ is performed at minimum input voltage and full load condition using (27) obtained from $i_{l k}$ and $i_{L m}$ waveforms.

$$
\begin{equation*}
L_{l k}=\frac{R_{L}}{f_{s}}\left[\frac{\left(V_{i n} / V_{o}\right)^{2}}{4 \cdot\left(1+L_{l k} / L_{m}^{\prime}\right)}-\frac{\left(V_{i n} / V_{o}\right) \cdot\left(1-D_{\max }\right)}{2 n}\right] \tag{27}
\end{equation*}
$$

Selecting the inductance values for a certain rated power $P_{o}$ and switching frequency $f_{s}$ depends upon the transformer turns ratio $n$, inductor ratio $L_{m}^{\prime} / L_{l k}$ and the maximum duty cycle $D_{\max }$ at full load calculated earlier. Here $L_{m}^{\prime}$ refers to equivalent magnetizing inductance referred to primary.

Now the transformer turns ratio $n=N_{s} / N_{p}$, is selected to maintain $D>0.5$, i.e., voltage regulation with load and fuel cell stack voltage variation given by

$$
\begin{equation*}
D=1-\frac{2 n \cdot V_{o}}{V_{i n}}\left[\frac{\left(V_{i n} / V_{o}\right)^{2}}{4 \cdot\left(1+L_{l k} / L_{m}{ }^{\prime}\right)}-\frac{L_{l k} \cdot f_{s}}{R_{L}}\right] \tag{28}
\end{equation*}
$$

and realizable value of $L_{l k}$ including transformer leakage (which is an issue mainly for power rating above 1 kW ) given by (27). Also, $n$ should be such that $L_{l k}$ is positive, using (27)

$$
\begin{equation*}
n>2 \cdot\left(1-D_{\max }\right) \cdot \frac{V_{o}}{V_{i n}} \cdot\left(1+L_{l k} / L_{m}{ }^{\prime}\right) \tag{29}
\end{equation*}
$$

Therefore, minimum value of $n=6.4$ for $L_{m}{ }^{\prime}=\infty$ (large value of magnetizing inductance) or $n=7$ for $L_{m}{ }^{\prime} / L_{l k}=10$. Fig. 4(a) shows the calculated values of $L_{l k}$ with respect to inductance ratio $L_{m}{ }^{\prime} / L_{l k}$ for three values of turns ratio $n$.

Inductance ratio $L_{m}{ }^{\prime} / L_{l k}$ is selected based on the ZVS range, and main switch RMS current given by (30), which should be low for high efficiency.

RMS current through the main switch is given by

$$
\begin{equation*}
I_{s v, r m s}=\sqrt{I_{i n}^{2}\left[\frac{3}{4}-\frac{D}{2}+\frac{T_{D R}}{3 T_{s}}\right]+\left(I_{L m, p e a k}^{\prime}\right)\left[\frac{2}{3}+\frac{D}{3}-\frac{4 T_{D R}}{3 T_{s}}\right]+I_{i n} I_{L m, p e a k}^{\prime}\left[D-1+\frac{T_{D R}}{3 T_{s}}\right]} \tag{30}
\end{equation*}
$$

Here $T_{D R}$ is rectifier diode conduction time given by

$$
\begin{equation*}
T_{D R}=\frac{n \cdot V_{i n}}{2 \cdot V_{o} \cdot f_{s}\left(1+\frac{L_{l k}}{L_{m}^{\prime}}\right)} \tag{31}
\end{equation*}
$$

During derivation, snubber charging/discharging intervals ( $t_{1}-$ $t_{3}, t_{5}-t_{7}, t_{10}-t_{12}, t_{14}-t_{16}$ ) of short duration are neglected.

Fig. 4(b) shows the calculated values of switch RMS current with respect to $L_{m}{ }^{\prime} / L_{l k}$ for four values of turns ratio $n$. Smaller value of $L_{m}{ }^{\prime} / L_{l k}$ will achieve ZVS at light load but increase peak and rms currents through the switches, leading to low efficiency of the converter.

For smaller turns ratio, i.e., $n=7$, value of $L_{l k}$ is low (Fig. 4(a)) and it reduces ZVS range as seen in (30). For higher transformer turns ratio, i.e., $n=10$, value of $L_{l k}$ is high (Fig. 4(b)) and increases ZVS range. Choosing a design (at 22 V , full load) with smaller value of $D$, say 0.6 for example (instead of 0.8 ), will result in smaller value of leakage inductance $L_{l k}$, which will not be able to store sufficient energy to maintain ZVS for the wider input voltage range and light load conditions. Also, choosing a design (at 22 V , full load) according to Fig. 4(a) for turns ratio $n>8$, for example $n$ $=9$ or 10 , will require higher transformer turns ratio, resulting in auxiliary switch duty cycle $D_{S a x}=2(1-D)>=1$, which is not possible and is the limitation of this converter. Therefore, $n=$ 8 with $D>0.5$ is chosen.

Turns ratio $n=8$ gives realizable value of $L_{l k}$, maintains voltage regulation at light load for given wide input voltage variation. Therefore, transformer turns ratio $n=8$ is selected.

Fig. 4(b) indicates that for a given value of $n$, switch rms current decreases as the ratio $L_{m}{ }^{\prime} / L_{l k}$ increases. For the selected value of $n=8$, reduction in rms current is negligible for $L_{m}{ }^{\prime} / L_{l k}$ $>25$. Therefore, an inductance ratio of $L_{m}{ }^{\prime} / L_{l k}=25$ is selected.

From the above discussions, using $D_{\max }=0.8, n=8$ and $L_{m}{ }^{\prime} / L_{l k}=25$, calculated values of inductances are $L_{l k}=0.4 \mu \mathrm{H}$ and $L_{m}=0.64 \mathrm{mH}$.
(4) Values of input boost inductor is given by

$$
\begin{equation*}
L=\left(V_{i n}\right)(D-0.5) /\left[\left(\Delta I_{i n}\right)\left(f_{s}\right)\right] \tag{32}
\end{equation*}
$$

where $\Delta I_{i n}$ is the boost inductor ripple current.
For $\Delta I_{i n}=0.5 \mathrm{~A}, L=132 \mu \mathrm{H}$. Maximum voltage across the inductor $=V_{C a}=55 \mathrm{~V}$, given by (3).
(5) Inductors' ratings: The RMS current through the leakage and magnetizing inductances are

$$
\begin{equation*}
I_{L l k, r m s}=\sqrt{I_{i n}^{2}\left[\frac{8 T_{D R}}{3 T_{s}}\right]+\left(I_{L m p p e a k}^{\prime}\right)^{2}\left[\frac{4 D}{3}-\frac{1}{3}\right]+I_{i n} \cdot I_{L m p e a t}^{\prime}\left[\frac{8}{3}(D-1)+\frac{4 T_{D R}}{T_{s}}\right]} \tag{33}
\end{equation*}
$$



Fig. 4. Variation of (a) value of leakage inductance $L_{l k}(\mathrm{H})$, and (b) switch RMS current (A), with respect to inductance ratio $L_{m}{ }^{\prime} / L_{l k}$ for various transformer turns ratio $n$ for the design example.

$$
\begin{equation*}
I_{L m, r m s}=\frac{I_{L m, p e a k}^{\prime}}{n} \sqrt{1-\frac{4 T_{D R}}{3 T_{s}}} \tag{34}
\end{equation*}
$$

Using (2), $I_{\text {Lm,peak }}^{\prime}=5.29 \mathrm{~A} . I_{L m, r m s}$ is calculated to be 0.55 A . Peak magnetizing inductance current $=I_{\text {Lm,peak }}^{\prime} / n=0.66 \mathrm{~A}$.
Using (31) and (33), $I_{l k, r m s}=20.11 \mathrm{~A}$. Peak current through $L_{l k}$ is, $I_{l k, \text { peak }}=2 I_{i n}+I_{L m, p e a k}^{\prime}=50.7 \mathrm{~A}$. Maximum voltage across $L_{l k}$ $=V_{o} / n=43.75 \mathrm{~V}$. Maximum voltage across $L_{m}=V_{o}=350 \mathrm{~V}$.
(6) Switch current ratings: RMS current through the main switches $I_{s w, r m s}$ can be calculated by (30). RMS current through the auxiliary switch is given by

$$
\begin{equation*}
I_{\text {auxsw }, r m s}=\left(I_{i n}+I_{L m, p e a k}^{\prime}\right) \cdot \sqrt{2(1-D) / 3} \tag{35}
\end{equation*}
$$

The values of $I_{s w, r m s}$ and $I_{a u x, r m s}$ are calculated to be 15 A and 10.22 A respectively.

Peak currents through main switches $I_{s w, p e a k}=2 I_{i n}+I_{\text {Lm,peak }}^{\prime}=$ 50.7 A and auxiliary switch $I_{\text {aux,peak }}=I_{i n}+I_{L m, p e a k}^{\prime}=28 \mathrm{~A}$.

Average current through auxiliary switch as well as antiparallel diodes is given by

$$
\begin{equation*}
I_{a u s s w, a v}=\left(I_{i n}+I_{L m, p e a k}^{\prime}\right) \cdot\left[\frac{(1-D)}{4}\right] \tag{36}
\end{equation*}
$$

Here, $I_{\text {auxsw,av }}=1.4 \mathrm{~A}$. Average current through the main switches $I_{s w, a v}=I_{i n} / 2=11.35 \mathrm{~A}$.
(7) Auxiliary capacitor: Substituting in (3), $V_{i n}=22 \mathrm{~V}$ and $D=$ $0.8, V_{C a}=55 \mathrm{~V}$. The value of auxiliary capacitor $C_{a}$ is

$$
\begin{equation*}
C_{a}=\frac{I_{C a, p e a k} \cdot \sqrt{2(1-D) / 3}}{4 \cdot \pi \cdot f_{s} \cdot \Delta V_{C a}} \tag{37}
\end{equation*}
$$

Peak current through $C_{a}$ is $I_{\text {Ca,peak }}=I_{i n}+I_{\text {Lm,peak }}^{\prime}=28 \mathrm{~A}$. For a ripple voltage of $\Delta V_{C a}=2 \mathrm{~V}, C_{a} \cong 4 \mu \mathrm{~F}$.

RMS current through auxiliary capacitor is

$$
\begin{equation*}
I_{C a, r m s}=I_{\text {Ca,peak }} \cdot \sqrt{\left(\frac{2}{3}(1-D)\right)} \tag{38}
\end{equation*}
$$

Here, $I_{\text {Carms }}=10.22 \mathrm{~A}$. Auxiliary capacitor carries a current of 200 kHz (twice the switching frequency).
(8) Output rectifier diodes: Average rectifier diode current is given by

$$
\begin{equation*}
I_{D R, a v g}=P_{o} /\left(2 V_{o}\right) \tag{39}
\end{equation*}
$$

Here, $I_{D R, a v g} \cong 0.7 \mathrm{~A}$. Voltage rating of rectifier diodes, $V_{D R}=$ $V_{o}=350 \mathrm{~V}$.
(9) Output capacitor: Value of output filter capacitor $C_{\mathrm{o}}$ is

$$
\begin{equation*}
C_{o}=\frac{\left(I_{0}\right) \cdot\left(\frac{T_{s}}{2}-T_{D R}\right)}{\Delta V_{o}} \tag{40}
\end{equation*}
$$

$\Delta V_{\mathrm{o}}=$ Allowable ripple in output voltage. $C_{\mathrm{o}}=4.9 \mu \mathrm{~F}$ for $\Delta V_{\mathrm{o}}$ $=0.75 \mathrm{~V}$. Its voltage rating is equal to $V_{o}=350 \mathrm{~V}$.
(10) Snubber design: The equation for the calculation of snubber capacitors is given by

$$
\begin{equation*}
\left(C_{1}+C_{4}+C_{S a x}\right)_{e f f}=\frac{t_{f} \cdot\left(I_{i n}+I_{L m, p e a k}^{\prime}\right)}{\frac{V_{i n}}{2(1-D)}} \tag{41}
\end{equation*}
$$

Here, $t_{f}=$ fall time of the switches during turn-off. $C_{1}=C_{4}=$ $C_{o s s, S 1} ; C_{a 1}=\left(C_{1}+C_{4}+C_{s a x}\right)_{e f f}-2 C_{o s s, S 1}$.
For the selected main and auxiliary switches IPP06CN10NG $\left(V_{d s}=100 \mathrm{~V}, I_{D}=100 \mathrm{~A}, R_{d s o n}=6.2 \mathrm{~m} \Omega, C_{o s s}=1 \mathrm{nF}, t_{f}=10\right.$ ns ), the calculated value of snubber capacitor across the auxiliary switch is $C_{a 1}=2.1 \mathrm{nF}$. Snubber capacitors' voltage rating is equal to switch voltage, given by (4) and is 55 V .
(11) ZVS Conditions: (A) To achieve ZVS of auxiliary switch, in interval 2, the dead-gap between the main switch gating signal $G_{S 2}$ and auxiliary switch gating signal $G_{S a x}$ should be of sufficient duration to allow charging of the snubber capacitors across the main switches $C_{2}$ and $C_{3}$ and discharging of snubber capacitor across the auxiliary switch $C_{a x}$, by the boost inductor current $I_{i n}$. The time required is given by

$$
\begin{equation*}
T_{d g 1}=\frac{\left(C_{2}+C_{3}+C_{a x}\right) \cdot\left(\frac{V_{i n}}{2(1-D)}\right)}{I_{i n}} \tag{42}
\end{equation*}
$$

(B) For ZVS of main switches, in interval 5 the charging of the snubber capacitor $C_{a x}$ and discharging of $C_{2}$ and $C_{3}$ should be done by the leakage inductance current in a quarter of the resonant period and is equal to the dead-gap between the auxiliary switch gating signal $G_{S a x}$ and main switch gating signal $G_{S 2}$ and is given by

$$
\begin{equation*}
T_{d g 2}=\frac{\pi}{2} \sqrt{L_{l k} \cdot\left(C_{2}+C_{3}+C_{a x}\right)} \tag{43}
\end{equation*}
$$

$T_{d g 1}=12 \mathrm{~ns}$ and $T_{d g 2}=65 \mathrm{~ns}$. Identical dead-gaps $T_{d g 1}=T_{d g 2}=$ 65 ns is provided between main and auxiliary gating signal.

The designed values are summarized in Table 1.
Table. 1. Values of the parameters obtained from design equations.

| $V_{i n}$ | $22-41 \mathrm{~V}$ | $V_{o}$ | 350 V |
| :---: | :---: | :---: | :---: |
| $P_{o}$ | 500 W | $f_{s}$ | 100 kHz |
| $L$ | $132 \mu \mathrm{H}$ | $C_{o}$ | $4.9 \mu \mathrm{~F}$ |
| $L_{l k}$ | $0.4 \mu \mathrm{H}$ | $L_{m}$ | 0.64 mH |
| $n$ | 8 | $C_{a}$ | $4 \mu \mathrm{~F}$ |

## IV. Simulation and Experimental Results

The designed converter rated at 500 W was first simulated using PSIM 9.0.4 and then built in the laboratory to verify the analysis, design and performance of the converter. Simulation results for two extreme operating conditions of $V_{i n}=22 \mathrm{~V}$, full load and $V_{\text {in }}=41 \mathrm{~V}, 10 \%$ load are presented in Fig. 5 and Fig. 6 , respectively. The components' values obtained from design and given in Table 1 are used as simulation parameters.
Simulation waveforms coincide with the theoretical operating waveforms shown in Fig. 2. When both the main switches are on, $v_{A B}=0, i_{L m}^{\prime}$ is flowing through $i_{l k}$ and are constant. Whenever, one main switch is off, $v_{A B}$ appears across the transformer and the current $i_{l k}$ and $i_{L m}$ change direction. At higher voltage and light load condition (Fig. 6), the duty cycle is low and therefore $v_{A B}$ appears for longer time. It makes the currents $i_{l k}$ and $i_{L m}$ to be constant for a very small duration and their appearance look like triangular in shape with higher peak value compared to full load condition. Figs. 5-6 show that the anti-parallel diodes of the switches (main and auxiliary) conduct prior to the conduction of corresponding switches causing zero voltage turn-on.


Fig. 5. Simulation waveforms at $V_{i n}=22 \mathrm{~V}$ and full load: (a) voltage $v_{A B}$, leakage inductance current $i_{l k}$, and magnetizing inductance current $i_{L m}(\mathrm{~b})$ main switches' currents $i_{S l}$ and $i_{S 2}$, auxiliary switch's current $i_{S a x}$ and voltage across auxiliary capacitor $V_{C a}$.


Fig. 6. Simulation waveforms at $V_{i n}=41 \mathrm{~V}$ and $10 \%$ load: (a) voltage $v_{A B}$, leakage inductance current $i_{k,}$, and magnetizing inductance current $i_{L m}(\mathrm{~b})$ main switches' currents $i_{S 1}$ and $i_{S 2}$, auxiliary switch's current $i_{S a x}$ and voltage across auxiliary capacitor $V_{C a}$.

It is clear that the leakage inductance current $i_{l k}$ is continuous due to the circulation of magnetizing current when all the H -bridge switches are on. It should be noticed that with increase in input voltage and/or reduction in load current, the duty cycle of main switches reduces, which results in increase in peak value of magnetizing inductance current. It adds to leakage inductance current to achieve ZVS of main switches even at such a wide variation in input voltage and load. At light load condition, anti-parallel body diode conduction time is increased due to magnetizing current assuring ZVS.


Fig. 7. Experimental laboratory prototype of 500 W current-fed full-bridge isolated dc/dc converter.

To obtain the simulation results for given input voltage ( 22 V in Fig. 5 and 41 V in Fig. 6) and for given load condition ( $245 \Omega$ at full load in Fig. 5 and $2450 \Omega$ at $10 \%$ load in Fig. 6) simulation is run for several HF cycles until the state variables reach a steady-state. Ideal components/devices were used.
Experimental prototype, as shown in Fig. 7, was built for the specifications and design given in Section III. The details are as follows: IPP06CN10NG (main and auxiliary switches); RUR-860 (rectifier diodes); HF transformer: PC40ETD44-Z ferrite core, primary turns $=9$, secondary turns $=72, L_{l k}$ (primary side) $=0.4 \mu \mathrm{H}, L_{m}$ (secondary side) $=332 \mathrm{mH}$; parallel inductor: T106-26, 83 turns, $L_{p}=0.641 \mathrm{mH}$; boost inductor: MPP Powder core, T250-40, 32 turns, $L=200 \mu \mathrm{H}$.

Due to imperfect ratio of $L_{l k} / L_{m}$ than the desired design value (given in the design section), an extra small size inductor $L_{p}$ is added in our experimental converter used for verification of analysis in our lab. In a practical industrial converter, one can control the magnetizing inductance value close to the required magnetizing inductance to avoid the use of external inductance. Also, slight changes in this value should not affect the performance too much.
Gating signals for the switches have been generated using Cypress PSoC 5 (Programmable system-on-chip) board.

IR2181 driver ICs are used for gating the MOSFETs. Variable resistors (rheostats) are used as load for testing. The developed converter prototype has been tested at full load and $10 \%$ load for $V_{\text {in }}=41 \mathrm{~V}$, and at full load and $20 \%$ load for $V_{\text {in }}$ $=22 \mathrm{~V}$. The experimental results are shown in Figs. 8-11.

Parts (b) to (e) of Figs. 8-11 clearly confirm the ZVS of main and auxiliary switch over wide variation in fuel cell voltage and load. In waveforms shown in part (b) of Figs. 8-11, gating signals $\left(v_{G S}\right)$ are applied to main switches after voltage across them ( $v_{D S}$ ) reaches zero. The ZVS turn on of main switches is also confirmed by part (d) of Figs. 8-11 since anti-parallel diode is conducting before the switch starts conducting.
Similarly, in part (e) of Figs. 8-11, anti-parallel diode of the auxiliary switch is conducting first causing ZVS turn-on of the auxiliary switch. This can be observed in gating signal ( $v_{G S}$ ) and voltage across the auxiliary switch ( $v_{D S}$ ) as shown in part (c) of Figs. 8-11. Voltage across the transformer $v_{A B}$ and the leakage inductance current $i_{l k}$ confirm ZCS of rectifier diodes (negligible ringing), as shown in part (a) of Figs. 8-11.

It is observed from these curves that the experimental values coincide with the calculated values. The experimental waveforms (Figs. 8-11) illustrate that the converter maintains ZVS for all switches over the complete range of load variation for wide input voltage range ( 22 to 41 V ). The designed converter maintains ZVS down to $20 \%$ load at $V_{\text {in }}=22 \mathrm{~V}$ and down to $5 \%$ load at $V_{\text {in }}=41 \mathrm{~V}$.

(c)

(d)

(e)

(f)

Fig. 8. Experimental waveforms at $V_{i n}=22 \mathrm{~V}$ and full load: (a) Voltage $v_{A B}$ ( $100 \mathrm{~V} / \mathrm{div}$ ) and leakage inductance current $i_{l k}(50 \mathrm{~A} / \mathrm{div})$, (b) main switch voltage $v_{D S}(50 \mathrm{~V} / \mathrm{div})$ and gate voltage $v_{G S}(10 \mathrm{~V} / \mathrm{div})$, (c) auxiliary switch voltage $v_{D S}(50 \mathrm{~V} / \mathrm{div})$ and gate voltage $v_{G S}(20 \mathrm{~V} / \mathrm{div})$, (d) main switch current $i_{S 1}\left(20 \mathrm{~A} /\right.$ div), (e) auxiliary switch current $i_{S a x}(20 \mathrm{~A} /$ div) and (f) magnetizing inductance current $i_{L m}(0.5 \mathrm{~A} / \mathrm{div})$.

(a)

(b)

(c)

(d)

(e)

(f)

Fig. 9. Experimental waveforms at $V_{i n}=41 \mathrm{~V}$ and full load: (a) Voltage $v_{A B}$ ( $50 \mathrm{~V} / \mathrm{div}$ ) and leakage inductance current $i_{l k}(50 \mathrm{~A} / \mathrm{div})$, (b) main switch voltage $v_{D S}(50 \mathrm{~V} / \mathrm{div})$ and gate voltage $v_{G S}(10 \mathrm{~V} / \mathrm{div})$, (c) auxiliary switch voltage $v_{D S}(50 \mathrm{~V} /$ div $)$ and gate voltage $v_{G S}(20 \mathrm{~V} / \mathrm{div})$, (d) main switch current $i_{S 1}(20 \mathrm{~A} /$ div $)$, (e) auxiliary switch current $i_{S a x}(10 \mathrm{~A} /$ div) and (f) magnetizing inductance current $i_{L m}(1 \mathrm{~A} /$ div $)$.

(a)

(b)

(c)

(d)

(e)

Fig. 10. Experimental waveforms at $V_{i n}=22 \mathrm{~V}$ and $20 \%$ load: (a) Voltage $v_{A B}(50 \mathrm{~V} / \mathrm{div})$ and leakage inductance current $i_{l k}(10 \mathrm{~A} / \mathrm{div})$, (b) main switch voltage $v_{D S}(50 \mathrm{~V} /$ div $)$, gate voltage $v_{G S}(20 \mathrm{~V} /$ div $)$ and current $i_{S 1}(10 \mathrm{~A} / \mathrm{div})$, (c) auxiliary switch voltage $v_{D S}(50 \mathrm{~V} / \mathrm{div})$ and gate voltage $v_{G S}(10 \mathrm{~V} / \mathrm{div})$, (d) auxiliary switch current $i_{S a x}(5 \mathrm{~A} /$ div) and (e) magnetizing inductance current $i_{L m}(0.5 \mathrm{~A} / \mathrm{div})$.

(a)

(b)

(c)

(d)

(e)

(f)

Fig. 11. Experimental waveforms at $V_{i n}=41 \mathrm{~V}$ and $10 \%$ load: (a) Voltage $v_{A B}$ ( $50 \mathrm{~V} / \mathrm{div}$ ) and leakage inductance current $i_{l k}(10 \mathrm{~A} / \mathrm{div})$, (b) main switch voltage $v_{D S}\left(50 \mathrm{~V} /\right.$ div) and gate voltage $v_{G S}(10 \mathrm{~V} / \mathrm{div})$, (c) auxiliary switch voltage $v_{D S}(50 \mathrm{~V} / \mathrm{div})$ and gate voltage $v_{G S}(10 \mathrm{~V} / \mathrm{div})$, (d) main switch current $i_{S 1}(10 \mathrm{~A} / \mathrm{div})$, (e) auxiliary switch current $i_{S a x}(5 \mathrm{~A} / \mathrm{div})$ and (f) magnetizing inductance current $i_{L m}(1 \mathrm{~A} / \mathrm{div})$.

## V. Summary and Conclusions

To achieve ZVS for wide source voltage variation and varying output power/load while maintaining high efficiency has been a challenge, especially for low voltage higher current input applications. A ZVS active-clamped current-fed full-bridge isolated converter has been re-studied in this paper. The magnetizing inductance increases the leakage inductance current value at light load and therefore, the energy stored in leakage inductance to maintain ZVS of main switches as well as auxiliary switch.
Detailed steady-state operation and analysis of current-fed full-bridge converter have been presented. Design to attain soft-switching over an extended range of input voltage and load i.e. output power has been presented. Simulation results using PSIM 9.0.4 have been presented. An experimental prototype of the converter rated at 500 W has been designed, built and tested for variations in input voltage and load in order to validate the analysis. Experimental results verify the accuracy of the analysis and show that the proposed configuration is able to maintain ZVS of all switches over a wide range of load and input voltage variation due to the variation in fuel flow and stack temperature. Theoretically, the converter is able to maintain ZVS till $20 \%$ load at 22 V and $5 \%$ load 41 V .
In a practical fuel cell application, when the load current drops due to reduced fuel flow, the light or reduced power below rated power is transferred at higher fuel cell voltage. It can be clearly seen and understood also from the fuel cell V-I characteristic. If the load current or power is around $10 \%$ of the rated power, then the fuel cell stack voltage increases nearly to 41 V . Hence, the possibility of the condition $V_{i n}=$ 22 V at $10 \%$ load is only during transition period when load is suddenly changed from full load to $10 \%$ due to fuel flow adjustment. Hence it is justifiable to have ZVS range of $20 \%$ load at low input voltage and below $10 \%$ at higher input voltage will cover the operating range at steady-state. Rated converter efficiency of $94 \%$ is obtained for the developed lab prototype rated at 500 W . The converter has limitation that duty cycle of the main switch should be greater than $50 \%$.

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